



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	Rds(on) Max	I _D Max T _C = +25°C		
-12V	11.7mΩ @ V _{GS} = -4.5V	-19A		
-120	18.6mΩ @ $V_{GS} = -2.5V$	-15A		

Description

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications. It is qualified to AEC-Q101, supported by a PPAP.

Applications

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

Features and Benefits

- Low RDS(ON) Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher **Density End Products**
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- ESD Protected Up to 3kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP1011LFVQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

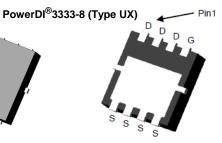
https://www.diodes.com/quality/product-definitions/

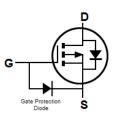
Mechanical Data

- Case: PowerDI®3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.072 grams (Approximate)









Top View

Bottom View Pin Configuration

Equivalent Circuit

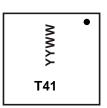
Ordering Information (Note 4)

Part Number	Case	Packaging
DMP1011LFVQ-7	PowerDI [®] 3333-8 (Type UX)	2,000/Tape & Reel
DMP1011LFVQ-13	PowerDI [®] 3333-8 (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



T41 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 for 2021) WW = Week Code 01 to 53

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-12	V		
Gate-Source Voltage	V _{GSS}	- 6	V		
Continuous Drain Current (Note 6) 1/ 4 51/	t < 10s	T _A = +25°C T _A = +70°C	lo	-13 -10	А
Continuous Drain Current (Note 6) V _{GS} = 4.5V	Steady State	T _C = +25°C T _C = +70°C	lo	-19 -15	А
Maximum Continuous Body Diode Forward Curr	Is	3	Α		
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			I _{DM}	70	Α
Avalanche Current (Note 7) L = 0.3mH			I _{AS}	24	Α
Avalanche Energy (Note 7) L = 0.3mH			Eas	86	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.05	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Davi	118	°C/W
Internal Resistance, Junction to Ambient (Note 5)	t < 10s	Reja	83.5	
Total Power Dissipation (Note 6)		PD	2.16	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	57	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	R _{θJA}	40.3	
Thermal Resistance, Junction to Case (Note 6)		Rejc	11.7	
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

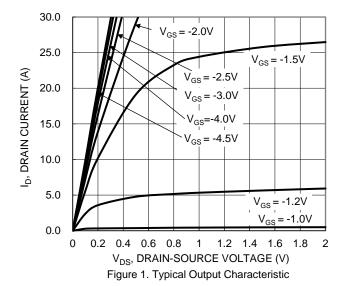
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)						•	
Drain-Source Breakdown Voltage	BV _{DSS}	-12	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	_	_	-1	μA	V _{DS} = -9.6V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	-100	nA	V _{GS} = -6V, V _{DS} = 0V	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	-0.6	_	-1.2	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance	Procon	_	9.8	11.7	mΩ	$V_{GS} = -4.5V$, $I_{D} = -12A$	
Static Drain-Source On-Resistance	RDS(ON)	_	14.6	18.6	11122	$V_{GS} = -2.5V, I_{D} = -9A$	
Diode Forward Voltage	V_{SD}	_	-0.8	-1.0	V	$V_{GS} = 0V$, $I_{S} = -16A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	913	_		V _{DS} = -6V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	458	_	pF		
Reverse Transfer Capacitance	Crss	_	53	_			
Gate Resistance	Rg	_	1.85	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (VGS = -6V)	Qg	_	9.5	_			
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	7.1	_	nC	Vps = -6V. lp = -12A	
Gate-Source Charge	Qgs	_	1.4	_	IIC	VDS = -6V, ID = -12A	
Gate-Drain Charge	Q _{gd}	_	1.1	_			
Turn-On Delay Time	t _{D(ON)}	_	6.3	_			
Turn-On Rise Time	t _R	_	2.6	_		$V_{DS} = -6V$, $V_{GS} = -4.5V$, $R_{L} = 1\Omega$, $R_{g} = 4.7\Omega$, $I_{D} = -12A$	
Turn-Off Delay Time	t _{D(OFF)}	_	14.4	_	ns		
Turn-Off Fall Time	t _F	_	3.9	_			
Body Diode Reverse Recovery Time	trr	_	13.5	_	ns	I _F = -12A, dI/dt = 100A/μs	
Body Diode Reverse Recovery Charge	Q_{RR}	_	2.5	_	nC	I _F = -12A, dI/dt = 100A/μs	

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 7. IAs and EAs ratings are based on low frequency and duty cycles to keep T_J = +25°C.
 8. Short duration pulse test used to minimize self-heating effect.
 9. Guaranteed by design. Not subject to production testing.





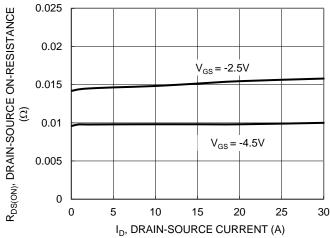


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

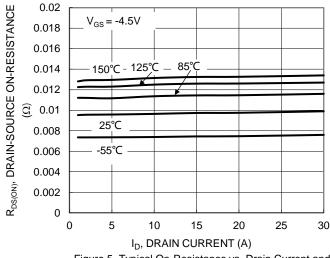
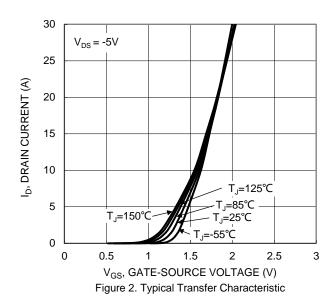


Figure 5. Typical On-Resistance vs. Drain Current and Temperature



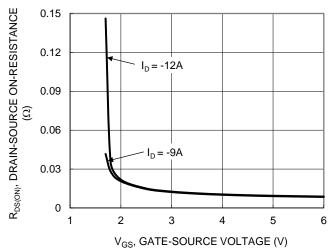


Figure 4. Typical Transfer Characteristic

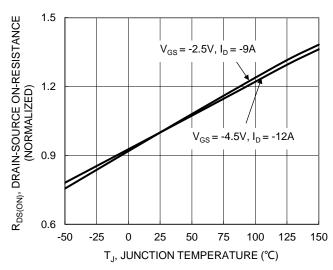


Figure 6. On-Resistance Variation with Temperature



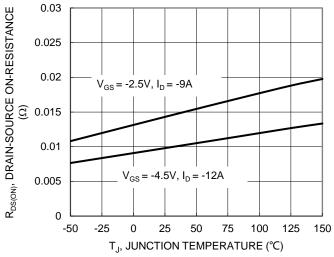


Figure 7. On-Resistance Variation with Temperature

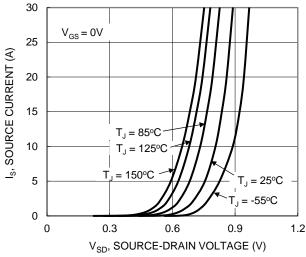
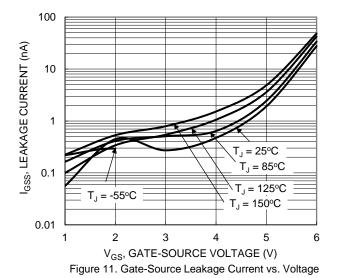


Figure 9. Diode Forward Voltage vs. Current



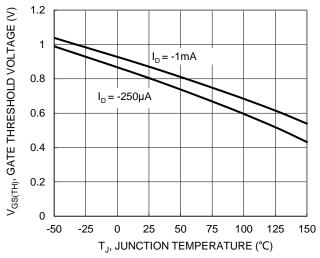


Figure 8. Gate Threshold Variation vs. Junciton Temperature

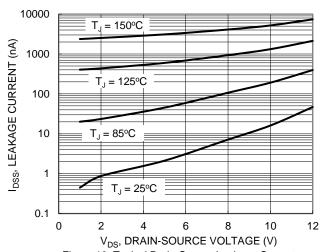


Figure 10. Typical Drain-Source Leakage Current vs.
Voltage

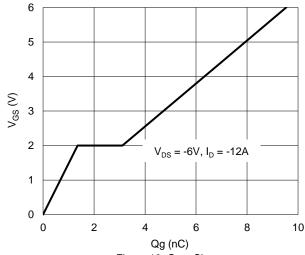
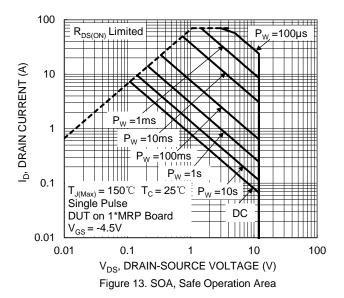


Figure 12. Gate Charge





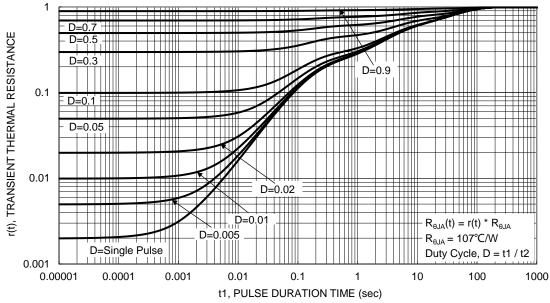


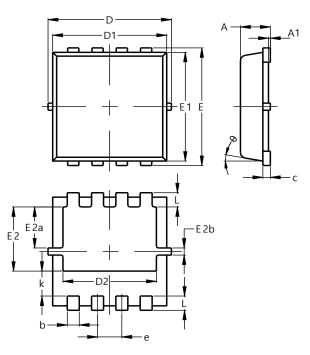
Figure 14. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI®3333-8 (Type UX)

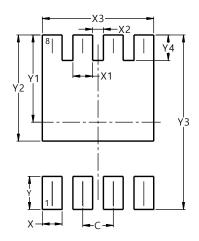


PowerDI3333-8						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E2a	0.95	1.35	1.15			
E2b	0.10	0.30	0.20			
е	0.65 BSC					
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI®3333-8 (Type UX)



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.370
Υ	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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